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Texas Instruments LT1004ID-2-5

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Datasheet of LT1004ID-2-5 - IC VREF SHUNT 2.5V 8SOIC

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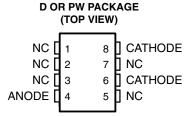
LT1004-1.2, LT1004-2.5 MICROPOWER INTEGRATED VOLTAGE REFERENCES

SLVS022M - JANUARY 1989 - REVISED MAY 2008

- Initial Accuracy
 - ±4 mV for LT1004-1.2
 - $-\pm 20$ mV for LT1004-2.5
- Micropower Operation
- Operates up to 20 mA
- Very Low Reference Impedance
- Applications:
 - Portable Meter Reference
 - Portable Test Instruments
 - Battery-Operated Systems
 - Current-Loop Instrumentation

description/ordering information

The LT1004 micropower voltage reference is a two-terminal band-gap reference diode designed to provide high accuracy and excellent temperature characteristics at very low operating currents. Optimizing the key parameters in the design, processing, and testing of the device results in specifications previously attainable only with selected units.



NC – No internal connection
Terminals 6 and 8 are internally connected.



NC - No internal connection

The LT1004 is a pin-for-pin replacement for the LM285 and LM385 series of references, with improved specifications. It is an excellent device for use in systems in which accuracy previously was attained at the expense of power consumption and trimming.

The LT1004C is characterized for operation from 0° C to 70° C. The LT1004I is characterized for operation from -40° C to 85° C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





Datasheet of LT1004ID-2-5 - IC VREF SHUNT 2.5V 8SOIC

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description/ordering information (continued)

ORDERING INFORMATION[†]

T _A	V _Z TYP	PACKAG	ìE [‡]	ORDERABLE PART NUMBER	TOP-SIDE MARKING
		0010 (D)	Tube of 75	LT1004CD-1-2	40.40
	407	SOIC (D)	Reel of 2500	LT1004CDR-1-2	4C-12
	1.2 V	TOOOD (DW)	Tube of 150	LT1004CPW-1-2	40.40
000 +- 7000		TSSOP (PW)	Reel of 2000	LT1004CPWR-1-2	4C-12
0°C to 70°C		0010 (D)	Tube of 75	LT1004CD-2-5	40.05
	0.5.1/	SOIC (D)	Reel of 2500	LT1004CDR-2-5	4C-25
	2.5 V	TOOOD (DW)	Tube of 150	LT1004CPW-2-5	40.05
		TSSOP (PW)	Reel of 2000	LT1004CPWR-2-5	4C-25
		COIC (D)	Tube of 75	LT1004ID-1-2	41.40
	1.2 V	SOIC (D)	Reel of 2500	LT1004IDR-1-2	4I-12
	1.2 V	TOOOD (DW)	Tube of 150	LT1004IPW-1-2	41.40
-40°C to 85°C		TSSOP (PW)	Reel of 2000	LT1004IPWR-1-2	4l-12
-40 C to 65 C		0010 (D)	Tube of 75	LT1004ID-2-5	41.05
	2.5 V	SOIC (D)	Reel of 2500	LT1004IDR-2-5	41-25
	2.5 V	TSSOP (PW)	Tube of 150	LT1004IPW-2-5	41-25
		13301 (1 W)	Reel of 2000	LT1004IPWR-2-5	41-23

[†] For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at http://www.ti.com.

symbol



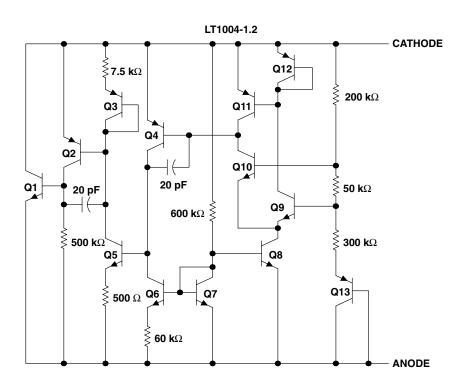


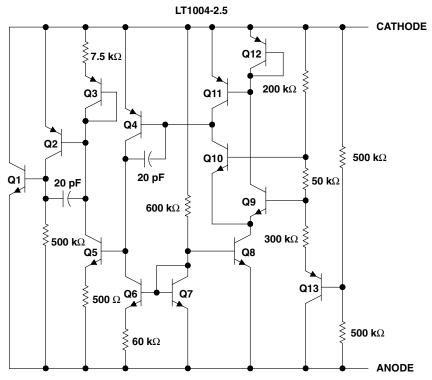
[‡] Package drawings, thermal data, and symbolization are available at http://www.ti.com/packaging.

LT1004-1.2, LT1004-2.5 **MICROPOWER INTEGRATED VOLTAGE RÉFERENCES**

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schematic





NOTE A: All component values shown are nominal.





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LT1004-1.2, LT1004-2.5 MICROPOWER INTEGRATED VOLTAGE REFERENCES

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Reverse current, I _R		
Package thermal impedance, θ_{JA} (see Notes 1 and 2):		
,	PW package 149°C/\	W
Operating virtual junction temperature, T _J		Ò,
Lead temperature 1,6 mm (1/16 inch) from case for 10	seconds 260°	Ċ
Storage temperature range, T _{stg}	–65°C to 150°	Ò,

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 - 2. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

			MIN	MAX	UNIT
_	Operating free oir temperature	LT1004C	0	70	°C
I A	Operating free-air temperature	LT1004I	-40	85	

electrical characteristics at specified free-air temperature

	DADAMETED	TEST			Lī	Г1004-1.	2	LT	1004-2.	5	LINUT
	PARAMETER	CONDITIONS	T _A ‡		MIN	TYP	MAX	MIN	TYP	MAX	UNIT
			2	25°C	1.231	1.235	1.239	2.48	2.5	2.52	
V_Z	V _Z Reference voltage	$I_Z = 100 \mu A$	Full	LT1004C	1.225		1.245	2.47		2.53	V
			range	LT1004I	1.225		1.245	2.47		2.53	
a.,	Average	$I_Z = 10 \mu A$] ,	2500		20					
α_{V_Z}	temperature coefficient of reference voltage§	I _Z = 20 μA	2	25°C					20		ppm/°C
		I - I (min) to 1 mA	z = I _Z (min) to 1 mA				1			1	
437	Change in	$I_Z = I_Z(MIII)$ to 1 MA					1.5			1.5	ma\/
ΔV_Z	reference voltage with current	1 1 m 4 to 00 m 4	2	25°C			10			10	mV
		$I_Z = 1 \text{ mA to } 20 \text{ mA}$	Ful	l range			20			20	
$\Delta V_Z/\Delta t$	Long-term change in reference voltage	I _Z = 100 μA	2	25°C		20			20		ppm/khr
I _Z (min)	Minimum reference current		Ful	l range		8	10		12	20	μΑ
	B.C		2	25°C		0.2	0.6		0.2	0.6	
Z _Z	Reference impedance	$I_Z = 100 \mu A$	Full range		1.5		1.5		Ω		
V _n	Broadband noise voltage	I _Z = 100 μA, f = 10 Hz to 10 kHz	2	25°C		60			120		μV

[‡] Full range is 0°C to 70°C for the LT1004C and -40°C to 85°C for the LT1004I.



[§] The average temperature coefficient of reference voltage is defined as the total change in reference voltage divided by the specified temperature range.



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LT1004-1.2, LT1004-2.5 MICROPOWER INTEGRATED VOLTAGE REFERENCES

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TYPICAL CHARACTERISTICS

Table of Graphs

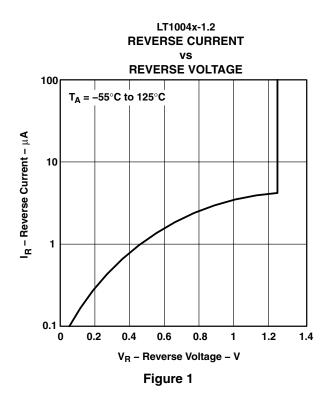
GRAPH TITLE	FIGURE
LT1004x-1.2	
Reverse current vs Reverse voltage	1
Reference-voltage change vs Reverse current	2
Forward voltage vs Forward current	3
Reference voltage vs Free-air temperature	4
Reference impedance vs Reference current	5
Noise voltage vs Frequency	6
Filtered output noise voltage vs Cutoff frequency	7
LT1004x-2.5	
Transient response	8
Reverse current vs Reverse voltage	9
Forward voltage vs Forward current	10
Reference voltage vs Free-air temperature	11
Reference impedance vs Reference current	12
Noise voltage vs Frequency	13
Filtered output noise voltage vs Cutoff frequency	14
Transient response	15

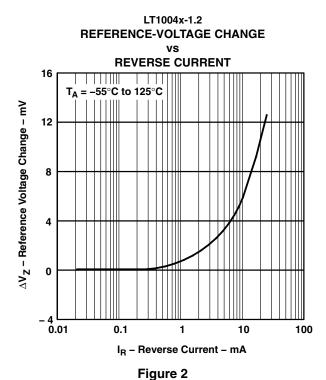


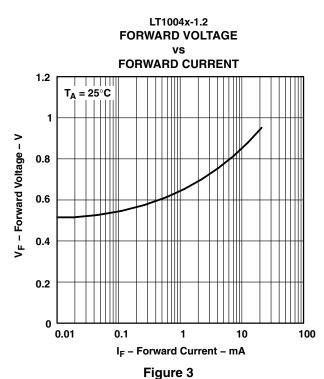
LT1004-1.2, LT1004-2.5 MICROPOWER INTEGRATED VOLTAGE REFERENCES

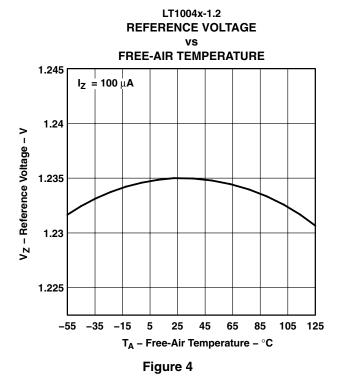
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TYPICAL CHARACTERISTICS†









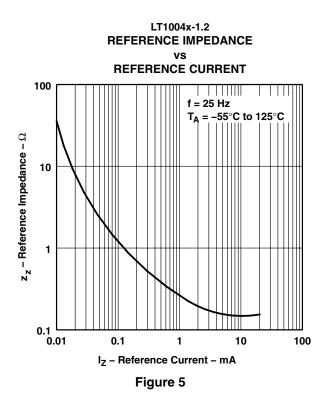
[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

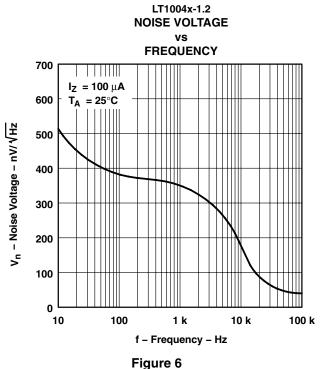


LT1004-1.2, LT1004-2.5 MICROPOWER INTEGRATED VOLTAGE REFERENCES

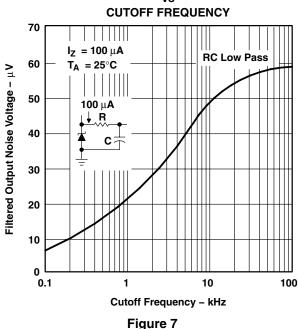
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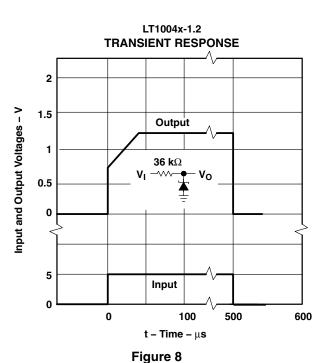
TYPICAL CHARACTERISTICS†











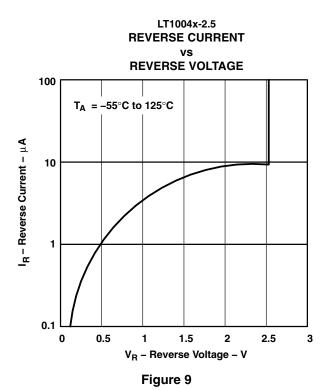
[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



LT1004-1.2, LT1004-2.5 MICROPOWER INTEGRATED VOLTAGE REFERENCES

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TYPICAL CHARACTERISTICS†



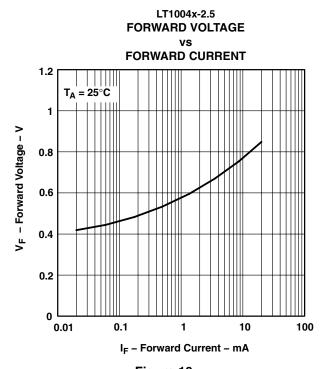


Figure 10

REFERENCE VOLTAGE vs FREE-AIR TEMPERATURE 2.52 $I_Z = 100 \,\mu\text{A}$ 2.515 2.51 V_Z - Reference Voltage - V 2.505 2.5 2.495 2.49 2.485 2.48 2.475 45 85 105 125 -55 -35 -15 25 65 T_A - Free-Air Temperature - °C

LT1004x-2.5

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



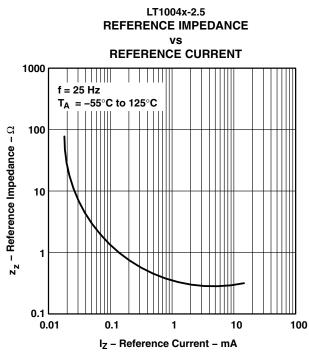
Figure 11

LT1004-1.2, LT1004-2.5 **MICROPOWER INTEGRATED VOLTAGE RÉFERENCES**

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LT1004x-2.5

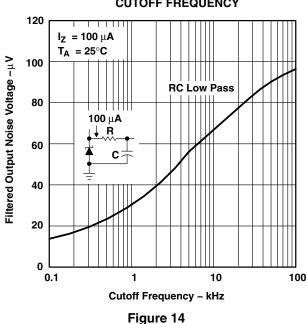
TYPICAL CHARACTERISTICS[†]

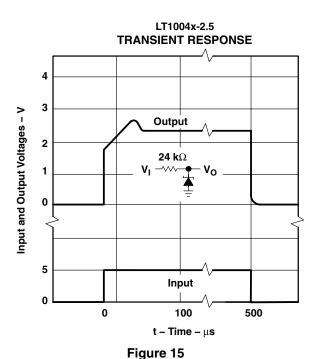


NOISE VOLTAGE ٧S **FREQUENCY** 1400 $I_Z = 100 \,\mu\text{A}$ $T_{\Delta} = 25^{\circ}C$ 1200 V_n - Noise Voltage - nV/√Hz 1000 800 600 400 200 0 10 100 10 k 1 k 100 k f - Frequency - Hz Figure 13

Figure 12

TL1004x-2.5 FILTERED OUTPUT NOISE VOLTAGE **CUTOFF FREQUENCY**





[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.





LT1004-1.2, LT1004-2.5 MICROPOWER INTEGRATED VOLTAGE REFERENCES

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APPLICATION INFORMATION

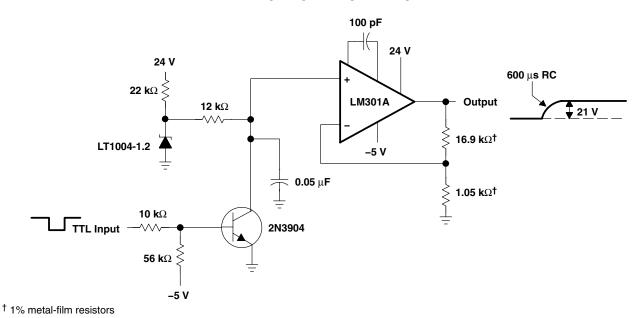


Figure 16. V_{I(PP)} Generator for EPROMs (No Trim Required)

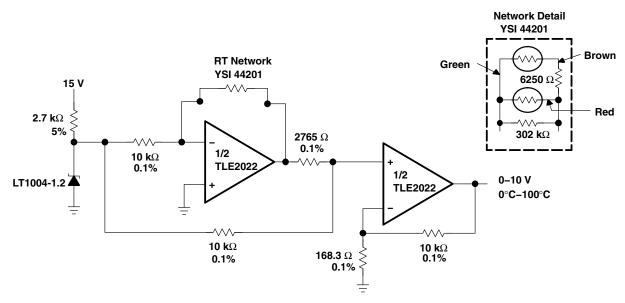


Figure 17. 0°C-to-100°C Linear-Output Thermometer



LT1004-1.2, LT1004-2.5 **MICROPOWER INTEGRATED VOLTAGE RÉFERENCES**

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APPLICATION INFORMATION

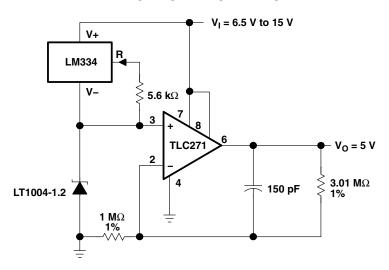
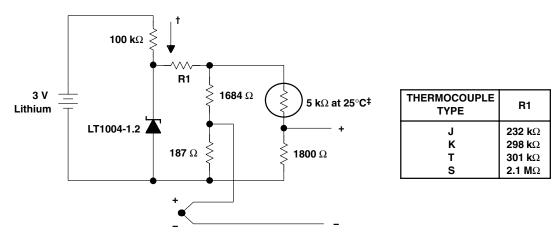


Figure 18. Micropower 5-V Reference



Figure 19. Low-Noise Reference

Figure 20. Micropower Reference From 9-V Battery



[†] Quiescent current ≅ 15 μA

NOTE A: This application compensates within ±1°C from 0°C to 60°C.

Figure 21. Micropower Cold-Junction Compensation for Thermocouples



[‡] Yellow Springs Inst. Co., Part #44007



LT1004-1.2, LT1004-2.5 MICROPOWER INTEGRATED VOLTAGE REFERENCES

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APPLICATION INFORMATION

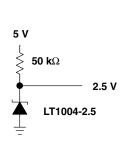


Figure 22. 2.5-V Reference

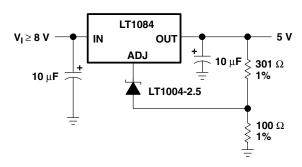
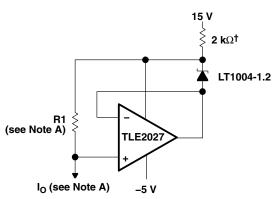


Figure 23. High-Stability 5-V Regulator

 $V_{CC+} \geq 5 \ V$



† May be increased for small output currents NOTE A: R1 $\approx \frac{2 \text{ V}}{I_O + 10 \,\mu\text{A}}$, $I_O = \frac{1.235 \text{ V}}{\text{R1}}$

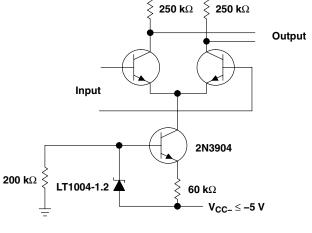
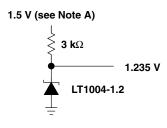


Figure 25. Amplifier With Constant Gain **Over Temperature**





NOTE A: Output regulates down to 1.285 V for $I_0 = 0$.

Figure 26. 1.2-V Reference From 1.5-V Battery

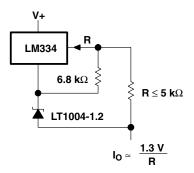


Figure 27. Terminal Current Source **With Low Temperature Coefficient**

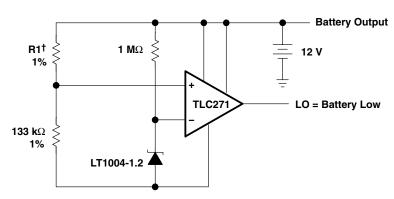




LT1004-1.2, LT1004-2.5 MICROPOWER INTEGRATED VOLTAGE REFERENCES

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APPLICATION INFORMATION



 † R1 sets trip point, 60.4 k Ω per cell for 1.8 V per cell.

Figure 28. Lead-Acid Low-Battery-Voltage Detector

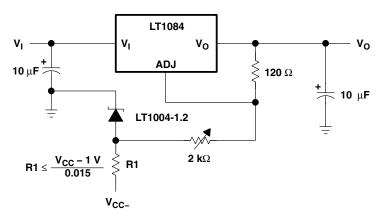


Figure 29. Variable-Voltage Supply





Datasheet of LT1004ID-2-5 - IC VREF SHUNT 2.5V 8SOIC

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PACKAGE OPTION ADDENDUM

om 10-Jun-2014

PACKAGING INFORMATION

Orderable Device		Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Sample
	(1)				•	(2)	(6)	(3)		(4/5)	
LT1004CD-1-2	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	4C-12	Sample
LT1004CD-2-5	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	4C-25	Sample
LT1004CD-2-5G4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	0 to 70		Sample
LT1004CDG4-1-2	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	4C-12	Sample
LT1004CDR-1-2	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	4C-12	Sample
LT1004CDR-2-5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	4C-25	Sample
LT1004CDRG4-2-5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	4C-25	Sample
LT1004CLP-1-2	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI	0 to 70		
LT1004CLP-2-5	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI	0 to 70		
LT1004CPW-1-2	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	4C-12	Sample
LT1004CPWR-1-2	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	4C-12	Sample
LT1004CPWR-2-5	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	4C-25	Sample
LT1004ID-1-2	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	4I-12	Sample
LT1004ID-2-5	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	41-25	Sample
LT1004IDG4-1-2	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	4I-12	Sample
LT1004IDG4-2-5	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	41-25	Sample
LT1004IDR-1-2	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	4I-12	Sample
LT1004IDR-2-5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	41-25	Sample

Addendum-Page 1



Distributor of Texas Instruments: Excellent Integrated System Limited Datasheet of LT1004ID-2-5 - IC VREF SHUNT 2.5V 8SOIC

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PACKAGE OPTION ADDENDUM

10-Jun-2014

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LT1004IDRE4-2-5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	41-25	Samples
LT1004IDRG4-1-2	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	41-12	Samples
LT1004ILP-2-5	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI	-40 to 85		
LT1004IPW-1-2	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	41-12	Samples
LT1004IPW-2-5	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	41-25	Samples
LT1004IPWR-1-2	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	41-12	Samples
LT1004IPWR-2-5	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	41-25	Samples
LT1004MD-1-2	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-55 to 125		
LT1004MD-2-5	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-55 to 125		
LT1004MDR-1-2	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-55 to 125		
LT1004MDR-2-5	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-55 to 125		
LT1004MLP-1-2	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI	-55 to 125		
LT1004MLP-2-5	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI	-55 to 125		

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): Til defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in the component is otherwise considered Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in the companion of t

in homogeneous material)

Addendum-Page 2



Distributor of Texas Instruments: Excellent Integrated System LimitedDatasheet of LT1004ID-2-5 - IC VREF SHUNT 2.5V 8SOIC

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PACKAGE OPTION ADDENDUM

www.ti.com 10-Jun-2014

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width

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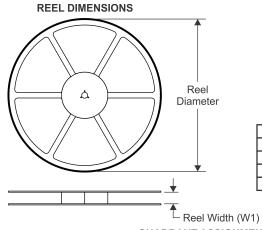
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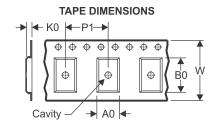


PACKAGE MATERIALS INFORMATION

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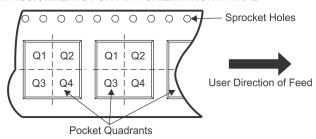
TAPE AND REEL INFORMATION





- A0 Dimension designed to accommodate the component width
- B0 Dimension designed to accommodate the component length
- K0 Dimension designed to accommodate the component thickness
- W Overall width of the carrier tape
- P1 Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All diffierisions are florilina												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LT1004CDR-1-2	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LT1004CDR-1-2	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LT1004CDR-2-5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LT1004CPWR-1-2	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LT1004CPWR-2-5	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LT1004IDR-1-2	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LT1004IDR-2-5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LT1004IPWR-1-2	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LT1004IPWR-2-5	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

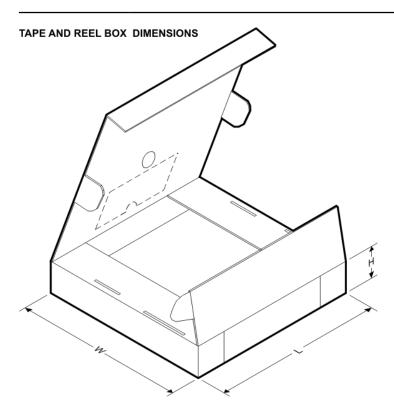
Datasheet of LT1004ID-2-5 - IC VREF SHUNT 2.5V 8SOIC

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PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

All difficultions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LT1004CDR-1-2	SOIC	D	8	2500	367.0	367.0	35.0
LT1004CDR-1-2	SOIC	D	8	2500	340.5	338.1	20.6
LT1004CDR-2-5	SOIC	D	8	2500	340.5	338.1	20.6
LT1004CPWR-1-2	TSSOP	PW	8	2000	367.0	367.0	35.0
LT1004CPWR-2-5	TSSOP	PW	8	2000	367.0	367.0	35.0
LT1004IDR-1-2	SOIC	D	8	2500	340.5	338.1	20.6
LT1004IDR-2-5	SOIC	D	8	2500	340.5	338.1	20.6
LT1004IPWR-1-2	TSSOP	PW	8	2000	367.0	367.0	35.0
LT1004IPWR-2-5	TSSOP	PW	8	2000	367.0	367.0	35.0

Datasheet of LT1004ID-2-5 - IC VREF SHUNT 2.5V 8SOIC

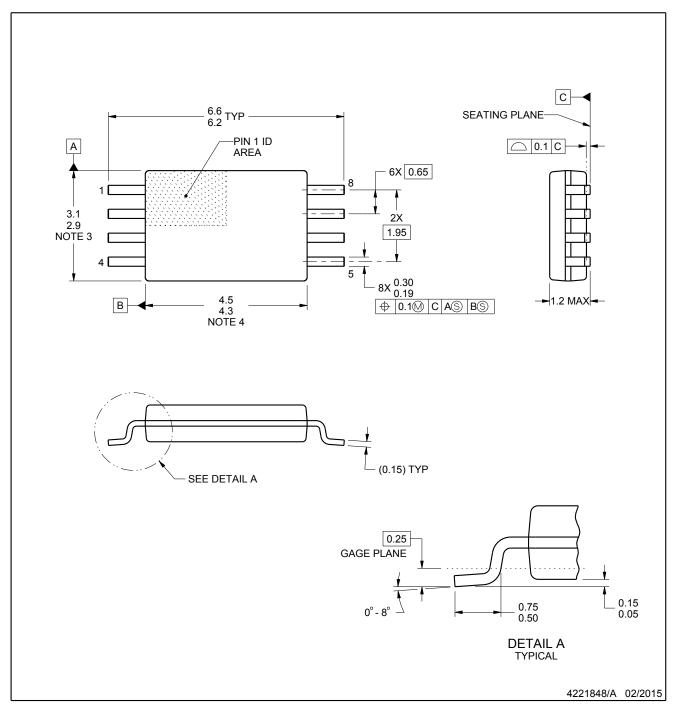
PW0008A



TSSOP - 1.2 mm max height

PACKAGE OUTLINE

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



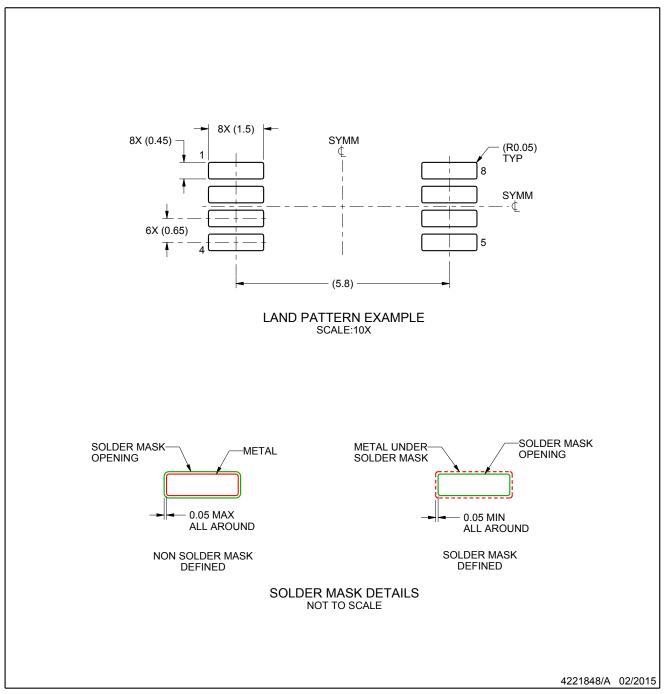


EXAMPLE BOARD LAYOUT

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



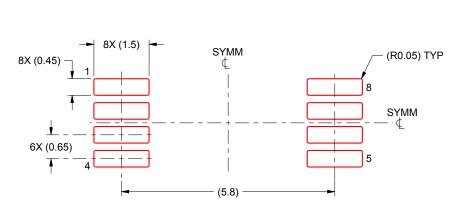


EXAMPLE STENCIL DESIGN

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE BASED ON 0.125 mm THICK STENCIL SCALE:10X

4221848/A 02/2015

NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.

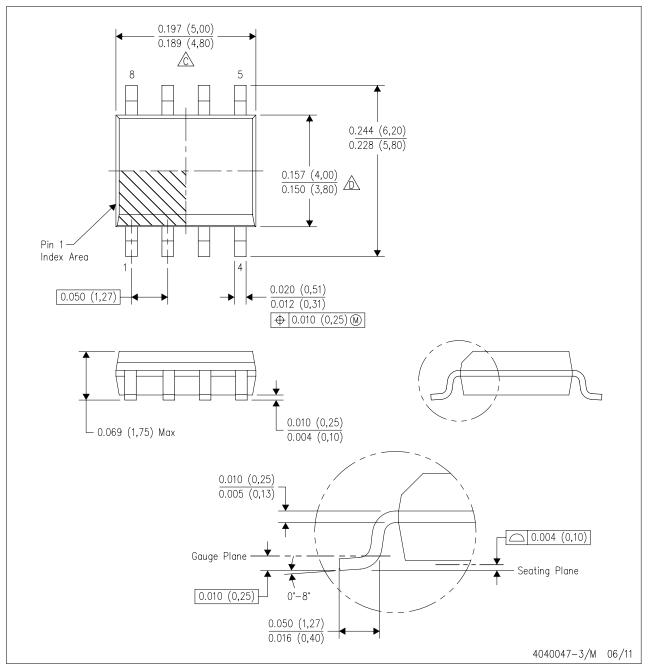




MECHANICAL DATA

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



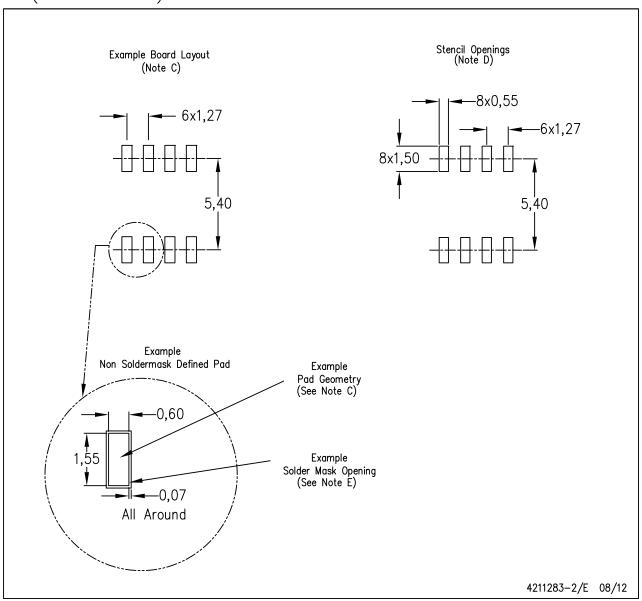




LAND PATTERN DATA

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



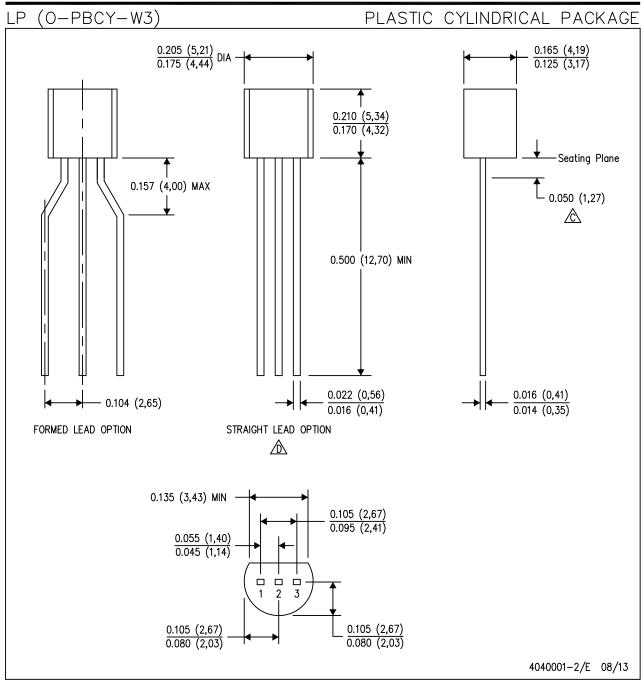
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





MECHANICAL DATA



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Lead dimensions are not controlled within this area.

 $\stackrel{\frown}{\Omega}$ Falls within JEDEC TO-226 Variation AA (TO-226 replaces TO-92).

E. Shipping Method:

Straight lead option available in bulk pack only.

Formed lead option available in tape & reel or ammo pack.

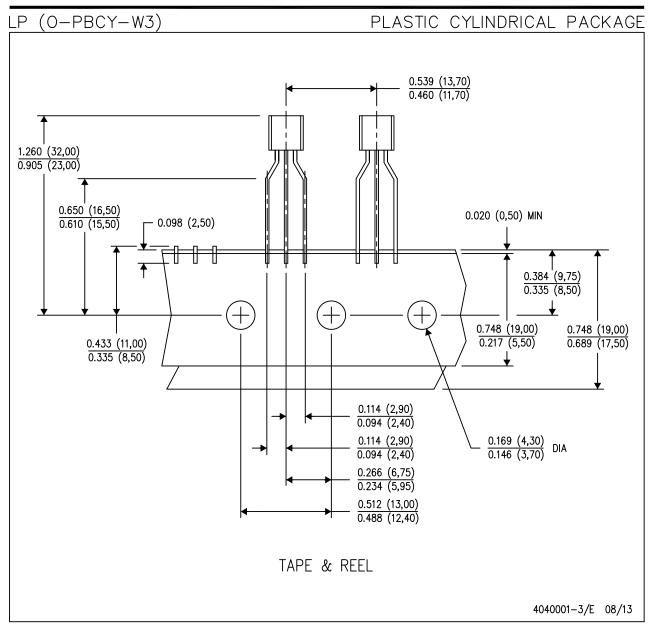
Specific products can be offered in limited combinations of shipping mediums and lead options.

Consult product folder for more information on available options.





MECHANICAL DATA



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Tape and Reel information for the Formed Lead Option package.





Datasheet of LT1004ID-2-5 - IC VREF SHUNT 2.5V 8SOIC

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